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RK7002A

Transistors

Switching (60V, 300mA)

RK7002A

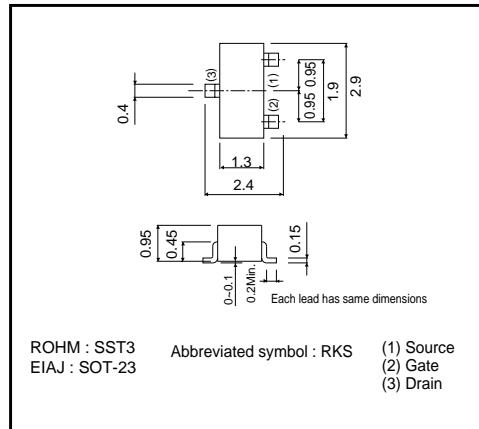
● Features

- 1) Low on-resistance.
 - 2) High ESD
 - 3) High-speed switching.
 - 4) Low-voltage drive (4V).
 - 5) Easily designed drive circuits.
 - 6) Easy to use in parallel.

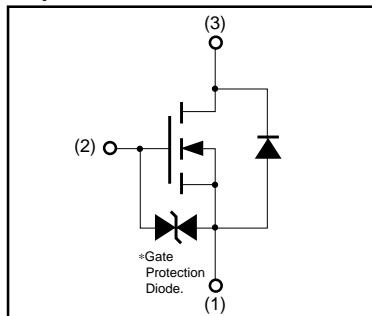
• Structure

Silicon N-channel MOSFET transistor

● **External dimensions** (Units : mm)



● Equivalent circuit



- * A protection diode has been built in between the gate and the source to protect against static electricity when the product is in use.
Use the protection circuit when fixed voltages are exceeded.

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V _{DSS}	60	V	
Gate-source voltage	V _{GSS}	±20	V	
Drain current	Continuous	I _D	300	mA
	Pulsed	I _{DP} *1	1.2	A
Drain reverse current	Continuous	I _{DR}	300	mA
	Pulsed	I _{DRP} *1	1.2	A
Total power dissipation	P _D *2	200	mW	
Channel temperature	T _{ch}	150	°C	
Storage temperature	T _{stg}	-55~+150	°C	

*1 Pw≤10μs, Duty cycle≤1%

*2 When using 1×0.75×0.062 inch glass epoxy board.

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate leakage current	I _{GSS}	—	—	±10	μA	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR) DSS}	60	—	—	V	I _D =10μA, V _{GS} =0V
Drain cutoff current	I _{DS}	—	—	1	μA	V _{DS} =60V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	1	—	2.5	V	V _{DS} =10V, I _D =1mA
Drain-source on-state resistance	R _{DS (on)} ^{*1}	—	0.7	1.0	Ω	I _D =300mA, V _{GS} =10V
		—	1.1	1.5		I _D =300mA, V _{GS} =4V
Forward transfer admittance	Y _{fs} ^{*1}	200	—	—	mS	V _{DS} =10V, I _D =300mA
Input capacitance	C _{iss}	—	33	—	pF	V _{DS} =10V
Output capacitance	C _{oss}	—	14	—	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	—	9	—	pF	f=1MHz
Turn-on delay time	t _{d (on)} ^{*2}	—	6	—	ns	I _D =150mA, V _{DD} =30V
Rise time	t _r ^{*2}	—	5	—	ns	V _{GS} =10V
Turn-off delay time	t _{d (off)} ^{*2}	—	13	—	ns	R _L =200Ω
Fall time	t _f ^{*2}	—	80	—	ns	R _{GS} =10Ω
Total gate charge	Q _g ^{*2}	—	3	6	nC	V _{DD} =30V
Gate-source charge	Q _{gs} ^{*2}	—	0.6	—	nC	V _{GS} =10V
Gate-drain charge	Q _{gd} ^{*2}	—	0.5	—	nC	I _D =200mA

*1 Pw≤300μs, Duty cycle≤1%

*2 Pulsed

●Packaging specifications

Type	Package	Taping
	Code	T116
	Basic ordering unit (pieces)	3000
RK7002A	○	

●Electrical characteristic curves

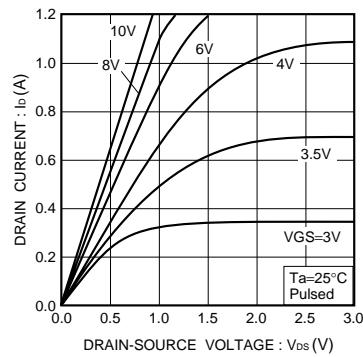


Fig.1 Typical output characteristics

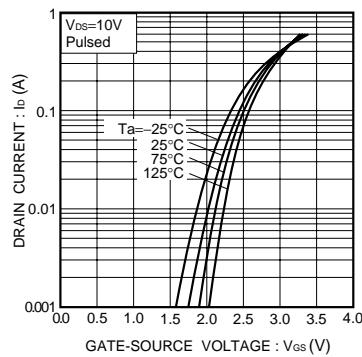


Fig.2 Typical transfer characteristics

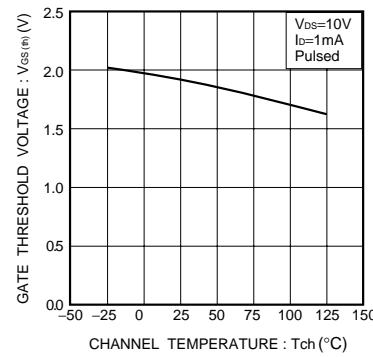
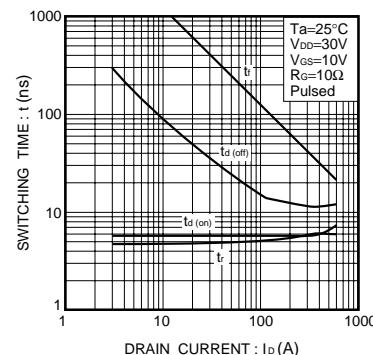
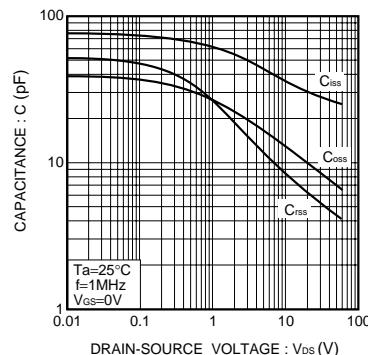
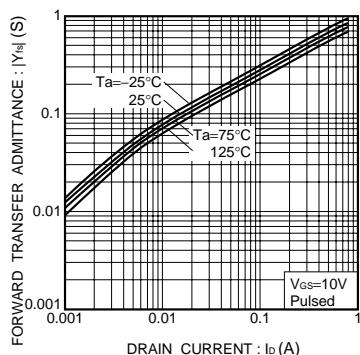
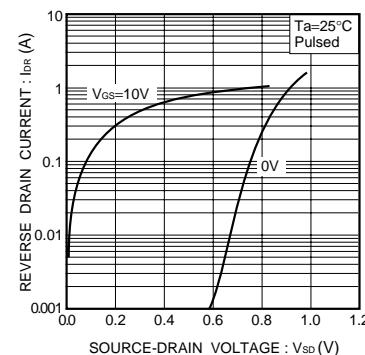
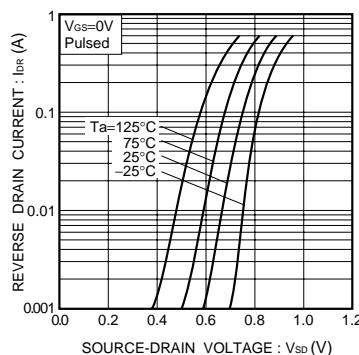
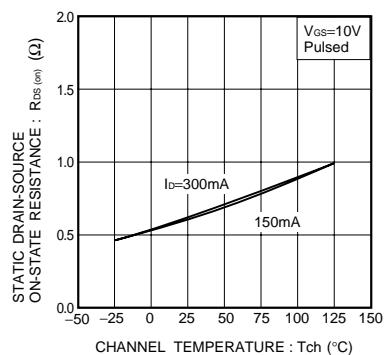
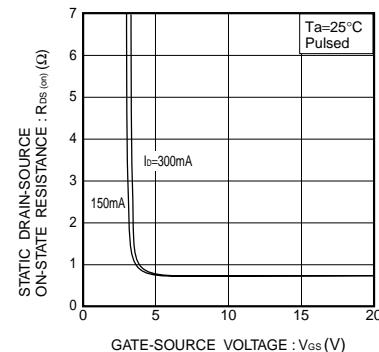
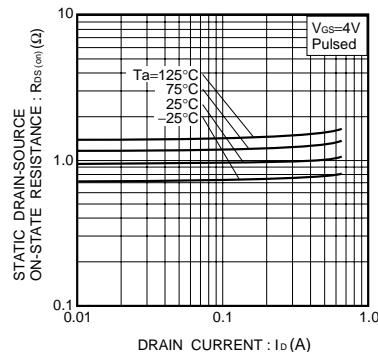
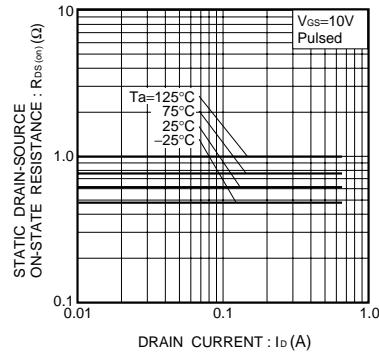


Fig.3 Gate threshold voltage vs. channel temperature

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●Switching characteristics measurement circuit

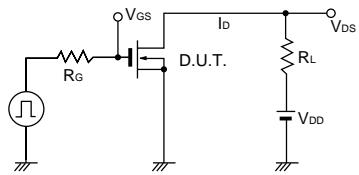


Fig.13 Switching time measurement circuit

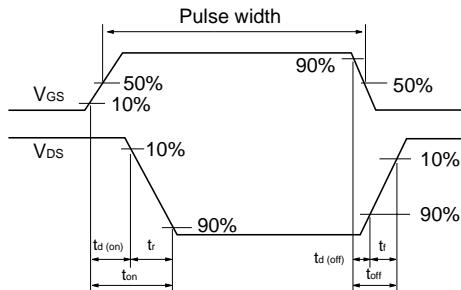


Fig.14 Switching time waveforms

Appendix

Notes

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